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Atty. Dkt. No. 039153-0371 (F0812)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#4/Amot

Applicant:

Lukanc et al.

Title:

METHOD OF ENHANCING GATE

PATTERNING PROPERTIES

WITH REFLECTIVE THARD MASK

Appl. No.:

09/845,654

Filing Date:

04/30/2001

Examiner:

Maldonado, Julio J.

Art Unit:

2823

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Commissioner for Patents, Washington, D.C. 20231, on the date below.

Jeanne Johnson

(Printed Name)

(Signature)

July 3, 2002

(Date of Deposit)

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AMENDMENT

Commissioner for Patents Box NON-FEE AMENDMENT Washington, D.C. 20231

Sir:

This communication is responsive to the Office Action dated April 10, 2002, concerning the above-referenced patent application.

Please amend the application as follows:

In the Specification:

Please replace paragraph numbers [0001], [0004], and [0032] with the following paragraphs pursuant to 37 C.F.R. § 1.121. The changes are shown explicitly in the attached "Version with Markings to Show Changes Made"

[0001] This application is related to U.S. patent Application No. 09/845,656, Attorney Docket No. 39153/366 (F0807), entitled USE OF SILICON CONTAINING IMAGING LAYER TO DEFINE SUB-RESOLUTION GATE STRUCTURES, and U.S. Patent Application No. 09/845,649, Attorney Docket No. 39153/367 (F0808), entitled BI-LAYER TRIM ETCH PROCESS TO FORM INTEGRATED CIRCUIT GATE STRUCTURES, both of which are assigned to the same assignee as this application and are filed on an even day herewith.

Q'